

RQ3E100BNTB

RQ3E100BNTB Information

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	Manufacturer	Rohm Semiconductor	
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET N-CH 30V 10A HSMT8	
	Package	8-PowerVDFN	
		For the pricing/inventory/lead time, please contact	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RQ3E100BNTB Specifications

Manufacturer Part Number	RQ3E100BNTB
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerVDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	22nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1100pF @ 15V
Vgs (Max)	$\pm 20\mathrm{V}$
FET Feature	-
Power Dissipation (Max)	2W (Ta)
Rds On (Max) @ Id, Vgs	10.4 mOhm @ 10A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-HSMT (3.2x3)
Package / Case	8-PowerVDFN
	Report errors?

RQ3E100BNTB Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RQ3E100BNTB Payment Methods





If you have any question about RQ3E100BNTB, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com